NSN 5962-01-290-2297

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N/a



View Online at https://aerobasegroup.com/nsn/5962-01-290-2297

view Online at https://aerobasegroup.com/hsh/5962-01-290-2297
Overall Length:
Between 0.930 inches and 0.975 inches
Overall Height:
0.330 inches
Body Length:
Between 0.930 inches and 0.975 inches
Body Width:
Between 0.245 inches and 0.300 inches
Body Height:
0.180 inches
Maximum Power Dissipation Rating:
500.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
3-state output and monolithic and programmed and low voltage and schottky
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Current Rating Per Characteristic:
16.00 milliamperes output
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
70.00 nanoseconds access
Memory Device Type:
Prom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
20 printed circuit
Shelf Life:

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Demilitarization:

Yes - demil/mli

Fiig:

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